

### N-Channel Super Junction Power MOSFET III

### **General Description**

The series of devices use advanced trench gate super junction technology and design to provide excellent RDS(ON) with low gate charge. This super junction MOSFET fits the industry's AC-DC SMPS requirements for PFC, AC/DC power conversion, and industrial power applications.

#### **Features**

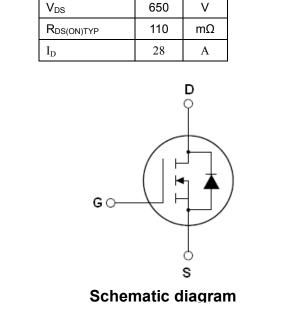
- •Optimized body diode reverse recovery performance
- •Low on-resistance and low conduction losses
- Small package
- Ultra Low Gate Charge cause lower driving requirements
- ●100% Avalanche Tested
- ROHS compliant

#### Application

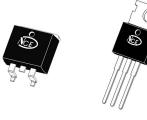
- Power factor correction (PFC)
- Switched mode power supplies(SMPS)
- Uninterruptible Power Supply (UPS)
- LLC Half-bridge

Package Marking And Ordering Information					
Device	Device Package	Marking			
NCE65TF130D	TO-263	NCE65TF130D			
NCE65TF130	TO-220	NCE65TF130			
NCE65TF130F	TO-220F	NCE65TF130F			

#### Tabla 1 Absolute Maximum Ratings (T₂=25℃)



### ♦ Intrinsic fast-recovery body diode





**TO-263** 

TO-220

TO-220F

Parameter	Symbol	NCE65TF130D NCE65TF130	NCE65TF130F	Unit
Drain-Source Voltage (V <sub>GS=0V</sub> )	VDS	65	50	V
Gate-Source Voltage (V <sub>DS</sub> =0V) AC (f>1 Hz)	Vgs	±	±30	
Continuous Drain Current at Tc=25°C	I <sub>D (DC)</sub>	28	28*	А
Continuous Drain Current at Tc=100°C	I <sub>D (DC)</sub>	18	18*	А
Pulsed drain current (Note 1)	I <sub>DM (pluse)</sub>	112	112*	А
Maximum Power Dissipation(Tc=25°C)	PD	260	35	W
Derate above 25°C		2.08	0.28	W/°C
Single pulse avalanche energy (Note 2)	Eas	676		mJ
Avalanche current <sup>(Note 1)</sup>	I <sub>AR</sub>	5.2		А
Repetitive Avalanche energy , $t_{\text{AR}}$ limited by $T_{\text{jmax}}$ (Note 1)	E <sub>AR</sub>	3.2		mJ



## NCE65TF130D,NCE65TF130,NCE65TF130F

Parameter	Symbol	NCE65TF130D NCE65TF130	NCE65TF130F	Unit
Drain Source voltage slope, $V_{DS} \leqslant$ 480 V,	dv/dt	50		V/ns
Reverse diode dv/dt, $V_{DS} \leq 480 V, I_{SD} < I_D$	dv/dt	50		V/ns
Operating Junction and Storage Temperature Range	$T_J,T_STG$	-55	+150	°C

\* limited by maximum junction temperature

#### Table 2. Thermal Characteristic

Parameter		mbol	NCE65TF130D NCE65TF130	NCE65TF130F		FU	Unit	
Thermal Resistance, Junction-to-Case (Maximum)		thJC	0.48	3.57		0	°C /W	
Thermal Resistance, Junction-to-Ambient (Maximum)		R <sub>thJA</sub>	62	80		0	C /W	
Table 3. Electrical Characteristics (TA=25 <sup>°</sup> Cunless otherwise noted)								
Parameter Sy			Condition	Min	Тур	Max	Unit	
On/off states								

On/off states						
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	V <sub>GS</sub> =0V I <sub>D</sub> =250µA	650			V
Zero Gate Voltage Drain Current(Tc=25℃)	I <sub>DSS</sub>	V <sub>DS</sub> =650V,V <sub>GS</sub> =0V			3	μA
Zero Gate Voltage Drain Current(Tc=125℃)	I <sub>DSS</sub>	V <sub>DS</sub> =650V,V <sub>GS</sub> =0V			100	μA
Gate-Body Leakage Current	I <sub>GSS</sub>	$V_{GS}$ =±20V, $V_{DS}$ =0V			±100	nA
Gate Threshold Voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> =V <sub>GS</sub> ,I <sub>D</sub> =250µA	3	3.5	4	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =14A		110	140	mΩ
Dynamic Characteristics						
Input Capacitance	C <sub>iss</sub>	V <sub>DS</sub> =50V,V <sub>GS</sub> =0V,		2070		pF
Output Capacitance	Coss	F=1.0MHz		120		pF
Effective output capacitance, energy related	C <sub>o(er)</sub>	V <sub>GS</sub> =0 V,V <sub>DS</sub> =0480 V		60		pF
Effective output consolitance, time related	6	ID=constant, V <sub>GS</sub> =0 V		311		ъĘ
Effective output capacitance, time related	C <sub>o(tr)</sub>	V <sub>DS</sub> =0480V		311		pF
Total Gate Charge	Qg	V <sub>DS</sub> =480V,I <sub>D</sub> =28A,		37.5		nC
Gate-Source Charge	$Q_gs$	V <sub>DS</sub> =400V,I <sub>D</sub> =20A, V <sub>GS</sub> =10V		13		nC
Gate-Drain Charge	$Q_{gd}$	VGS-10V		11.5		nC
Switching times						
Turn-on Delay Time	t <sub>d(on)</sub>			14		nS
Turn-on Rise Time	t <sub>r</sub>	V <sub>DD</sub> =380V,I <sub>D</sub> =14A,		12		nS
Turn-Off Delay Time	t <sub>d(off)</sub>	R <sub>G</sub> =2.3Ω,V <sub>GS</sub> =10V		65		nS
Turn-Off Fall Time	t <sub>f</sub>			11		nS
Source- Drain Diode Characteristics						
Source-drain current(Body Diode)	I <sub>SD</sub>	T <sub>c</sub> =25°C			28	А
Pulsed Source-drain current(Body Diode)	I <sub>SDM</sub>	1 <sub>C</sub> -23 C			112	А
Forward On Voltage	V <sub>SD</sub>	Tj=25°C,I <sub>SD</sub> =28A,V <sub>GS</sub> =0V		0.9	1.2	V
Reverse Recovery Time	trr			190		nS
Reverse Recovery Charge	Qrr	Tj=25°C,I <sub>F</sub> =14A,di/dt=100A/µs		2		uC
Peak Reverse Recovery Current	Irrm			21		А

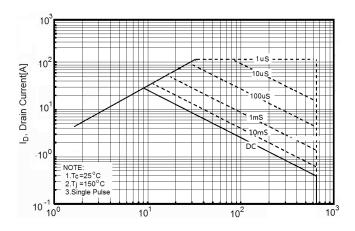
Notes 1.Repetitive Rating: Pulse width limited by maximum junction temperature

2. Tj=25  $^\circ\!\!\!\mathrm{C}$  ,VDD=50V,VG=10V, R\_G=25\Omega



### TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (curves)

#### Figure1. Safe operating area



#### Figure3. Source-Drain Diode Forward Voltage

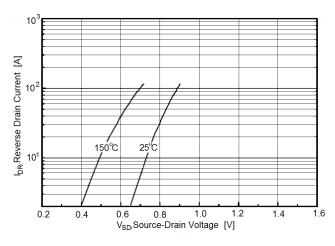
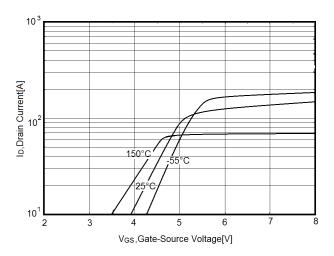


Figure 5. Transfer characteristics



#### Figure2. Safe operating area for TO-220F

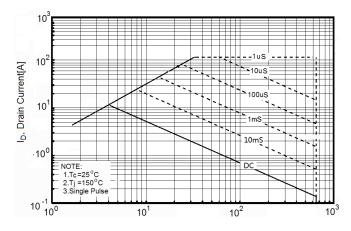


Figure4. Output characteristics

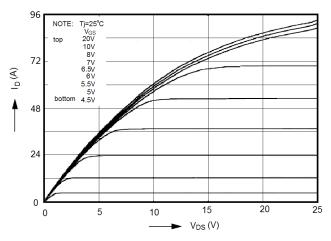
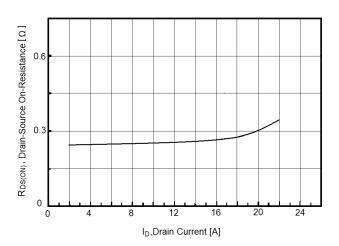


Figure6. Static drain-source on resistance

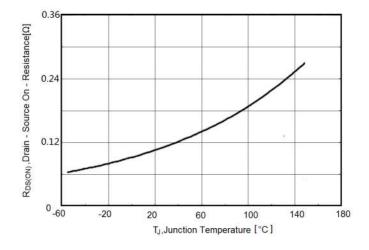




### NCE65TF130D,NCE65TF130,NCE65TF130F

#### Figure7. R<sub>DS(ON)</sub> vs Junction Temperature

#### Figure8. BV<sub>DSS</sub> vs Junction Temperature



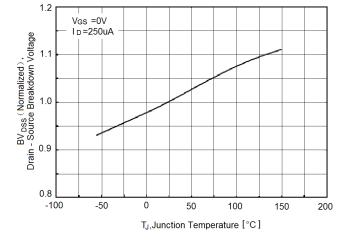


Figure9. Maximum I<sub>D</sub> vs Junction Temperature

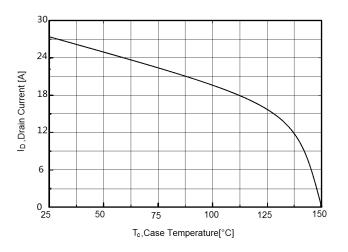


Figure10. Gate charge waveforms

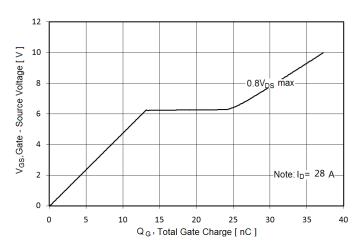


Figure11. Capacitance

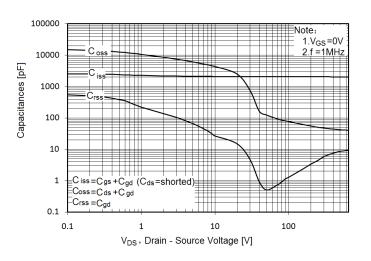
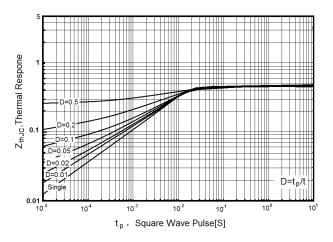
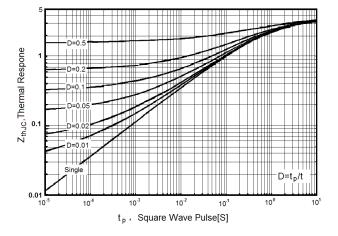


Figure12. Transient Thermal Impedance





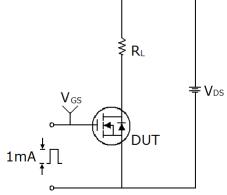
#### Figure13. Transient Thermal Impedance for TO-220F

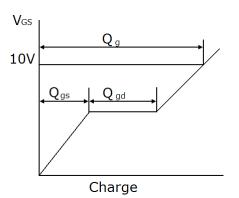




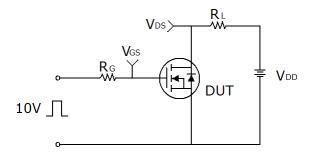
### Test circuit

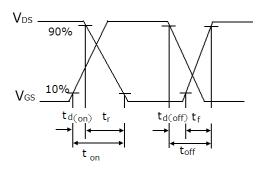
1) Gate charge test circuit & Waveform



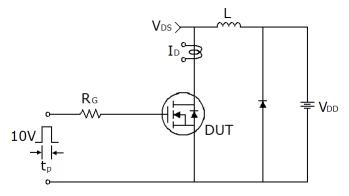


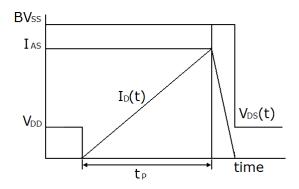
2) Switch Time Test Circuit:





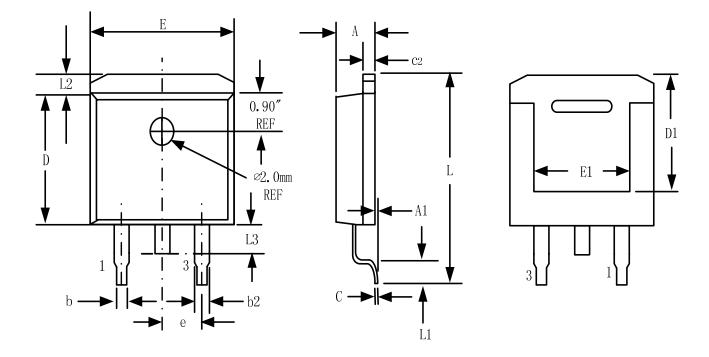
3) Unclamped Inductive Switching Test Circuit & Waveforms







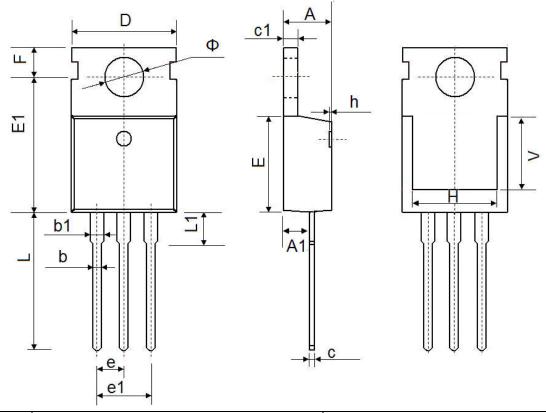
## **TO-263-3L Package Information**



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	4.32	4.57	0.170	0.180	
A1	-	0.25		0.010	
b	0.71	0.94	0.028	0.037	
b2	1.15	1.40	0.045	0.055	
С	0.46	0.61	0.018	0.024	
c2	1.22	1.40	0.048	0.055	
D	8.89	9.40	0.350	0.370	
D1	8.01	8.23	0.315	0.324	
E	10.04	10.28	0.395	0.405	
E1	7.88	8.08	0.310	0.318	
e	2.54	4 BSC	0.100 BSC		
L	14.73	15.75	0.580	0.620	
L1	2.29	2.79	0.090	0.110	
L2	1.15	1.39	0.045	0.055	
L3	1.27	1.77	0.050	0.070	



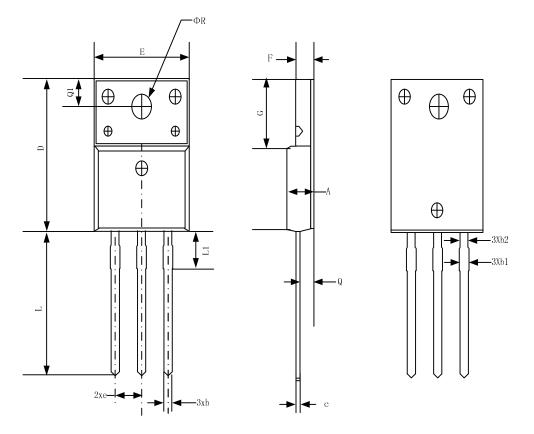
# TO-220-3L-C Package Information



Symbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
А	4.400	4.600	0.173	0.181	
A1	2.250	2.550	0.089	0.100	
b	0.710	0.910	0.028	0.036	
b1	1.170	1.370	0.046	0.054	
С	0.330	0.650	0.013	0.026	
c1	1.200	1.400	0.047	0.055	
D	9.910	10.250	0.390	0.404	
E	8.9500	9.750	0.352	0.384	
E1	12.650	12.950	0.498	0.510	
е	2.540	) TYP.	0.100	TYP.	
e1	4.980	5.180	0.196	0.204	
F	2.650	2.950	0.104	0.116	
Н	7.900	8.100	0.311	0.319	
h	0.000	0.300	0.000	0.012	
L	12.900	13.400	0.508	0.528	
L1	2.850	3.250	0.112	0.128	
V	7.500	7.500 REF.		REF.	
Ф	3.400	3.800	0.134	0.150	



## **TO-220F Package Information**



Sumbol	Dimensions	In Millimeters	Dimensions In Inches		
Symbol	Min.	Max.	Min.	Max.	
A	4.50	4.83	0.18	0.19	
b	0.70	0.91	0.03	0.04	
b1	1.20	1.47	0.05	0.06	
b2	1.10	1.38	0.04	0.05	
с	0.45	0.63	0.02	0.02	
D	15.67	16.07	0.62	0.63	
е	2.54	BSC	0.10 BSC		
E	9.96	10.36	0.39	0.41	
F	2.34	2.74	0.09	0.11	
G	6.48	6.90	0.26	0.27	
L	12.68	13.30	0.50	0.52	
L1	3.13	3.50	0.12	0.14	
Q	2.56	2.93	0.10	0.12	
Q1	3.20	3.40	0.13	0.13	
ΦR	3.08	3.28	0.12	0.13	



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